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BC856S 65 V, 100 mA PNP/PNP general-purpose transistor Rev. 02 – 19 February 2009 Produ

Product data sheet

1. Product profile

1.1 General description

PNP/PNP general-purpose transistor pair in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

1.2 Features

- Low collector capacitance
- Low collector-emitter saturation voltage
- Closely matched current gain
- Reduces number of components and board space
- No mutual interference between the transistors

1.3 Applications

General-purpose switching and amplification

1.4 Quick reference data

| Table 1. | Quick reference data | | | | | |
|-----------------|---------------------------|-------------------------------------|-----|-----|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| Per transistor | | | | | | |
| V_{CEO} | collector-emitter voltage | open base | - | - | -65 | V |
| I _C | collector current | | - | - | -100 | mA |
| h _{FE} | DC current gain | $V_{CE} = -5 V;$ $I_{C} = -2 mA$ | 110 | - | - | |

2. Pinning information

| Pin | Description | Simplified outline | Graphic symbol |
|-----|---------------|----------------------------------|----------------|
| 1 | emitter TR1 | | |
| 2 | base TR1 | | |
| 3 | collector TR2 | | |
| 4 | emitter TR2 | | |
| 5 | base TR2 | <u> </u> 1 <u> </u> 2 <u> </u> 3 | |
| 6 | collector TR1 | | 1 2 3 |
| | | | sym018 |



3. Ordering information

| Table 3. Order | ing inform | ation | |
|----------------|------------|--|---------|
| Type number | Package | | |
| | Name | Description | Version |
| BC856S | SC-88 | plastic surface-mounted package; 6 leads | SOT363 |

4. Marking

Table 4.Marking codes

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| BC856S | 5F* |

- [1] * = -: made in Hong Kong
 - * = p: made in Hong Kong
 - * = t: made in Malaysia
 - * = W: made in China

5. Limiting values

Table 5.Limiting values

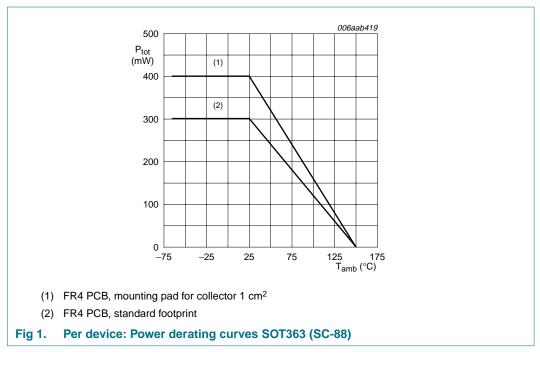
In accordance with the Absolute Maximum Rating System (IEC 60134).

| | | | · · | | |
|------------------|---------------------------|------------------------------|--------------|------|------|
| Symbol | Parameter | Conditions | Min | Max | Unit |
| Per transis | stor | | | | |
| V _{CBO} | collector-base voltage | open emitter | - | -80 | V |
| V _{CEO} | collector-emitter voltage | open base | - | -65 | V |
| V _{EBO} | emitter-base voltage | open collector | - | -5 | V |
| I _C | collector current | | - | -100 | mA |
| P _{tot} | total power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | <u>[1]</u> - | 220 | mW |
| | | | [2] _ | 250 | mW |
| Per device | | | | | |
| P _{tot} | total power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | <u>[1]</u> - | 300 | mW |
| | | | [2] _ | 400 | mW |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -65 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| | | | | | |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

65 V, 100 mA PNP/PNP general-purpose transistor



6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|--|-------------|--------------|-----|-----|------|
| Per transi | stor | | | | | |
| R _{th(j-a)} | thermal resistance from | in free air | <u>[1]</u> _ | - | 568 | K/W |
| jur | junction to ambient | | [2] _ | - | 500 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | - | - | 230 | K/W |
| Per device | 9 | | | | | |
| R _{th(j-a)} | thermal resistance from | in free air | <u>[1]</u> _ | - | 416 | K/W |
| | junction to ambient | | [2] _ | - | 313 | K/W |

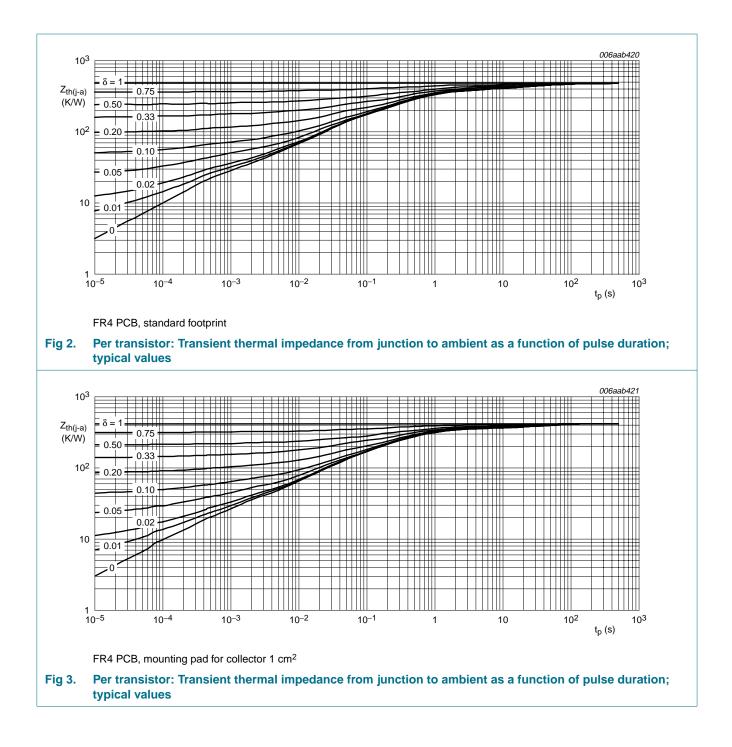
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

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65 V, 100 mA PNP/PNP general-purpose transistor

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7. Characteristics

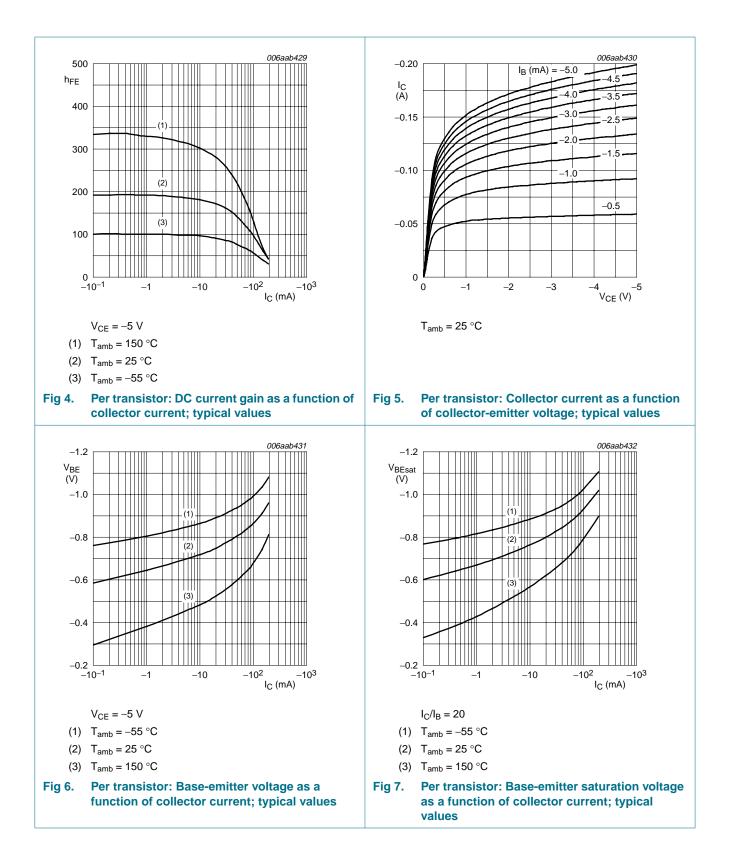
| Table 7.Characteristics $T_{amb} = 25 ^{\circ}C$ unless otherwise specified. | | | | | | |
|--|---|--|------|------|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| Per trans | Per transistor | | | | | |
| I _{CBO} collector-base cut-off current | collector-base cut-off | $V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}$ | - | - | -15 | nA |
| | $\label{eq:VCB} \begin{array}{l} V_{CB} = -30 \ \text{V}; \ \textbf{I}_{E} = 0 \ \text{A}; \\ T_{j} = 150 \ ^{\circ}\text{C} \end{array}$ | - | - | -5 | μA | |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$ | - | - | -100 | nA |
| h _{FE} | DC current gain | V_{CE} = -5 V; I_C = -2 mA | 110 | - | - | |
| | collector-emitter saturation voltage | $I_{C} = -10 \text{ mA};$ $I_{B} = -0.5 \text{ mA}$ | - | - | -100 | mV |
| | | $I_{\rm C} = -100 \text{ mA}; I_{\rm B} = -5 \text{ mA}$ | 1 - | - | -300 | mV |
| V _{BEsat} | base-emitter saturation voltage | I _C = -10 mA; I _B = -0.5 mA | - | 700 | - | mV |
| V _{BE} | base-emitter voltage | $I_C = -2 \text{ mA}; V_{CE} = -5 \text{ V}$ | -600 | -650 | -750 | mV |
| | | $I_{C} = -10 \text{ mA}; V_{CE} = -5 \text{ V}$ | - | - | -820 | mV |
| C _c | collector capacitance | $\begin{split} I_{\text{E}} &= i_{\text{e}} = 0 \text{ A}; \text{V}_{\text{CB}} = -10 \text{ V}; \\ \text{f} &= 1 \text{ MHz} \end{split}$ | - | - | 2.5 | pF |
| f _T | transition frequency | $I_{C} = -10 \text{ mA}; V_{CE} = -5 \text{ V};$ f = 100 MHz | 100 | - | - | MHz |
| | | | | | | |

[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02$.

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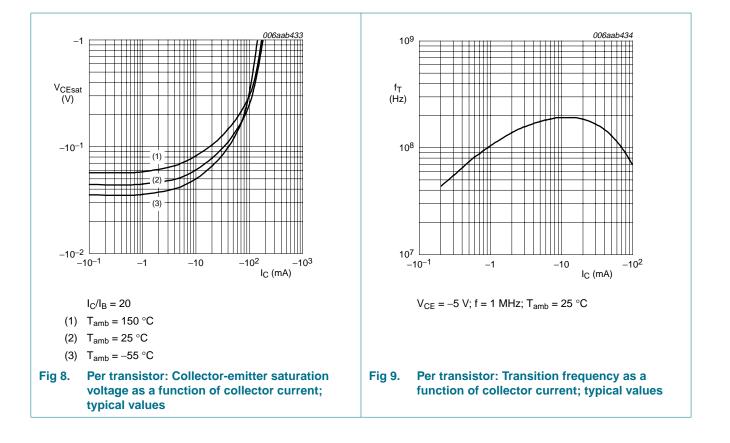
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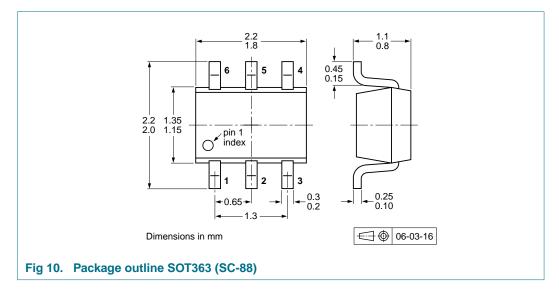
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8. Package outline



9. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Package Description | | Packing quantity | |
|---------------|------------------------------------|------------------------------------|------------|------------------|-------|
| | | | | 3000 | 10000 |
| BC856S SOT363 | 4 mm pitch, 8 mm tape and reel; T1 | [2] | -115 | -135 | |
| | | 4 mm pitch, 8 mm tape and reel; T2 | <u>[3]</u> | -125 | -165 |

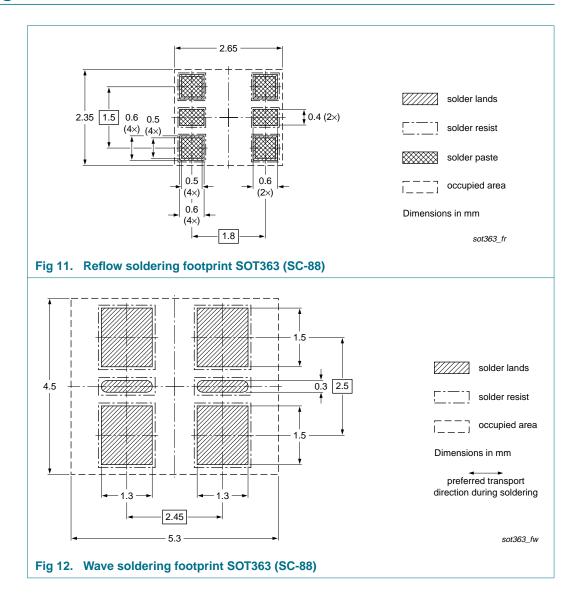
[1] For further information and the availability of packing methods, see <u>Section 13</u>.

[2] T1: normal taping

[3] T2: reverse taping

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10. Soldering



11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|----------------|---|-----------------------------|---------------|------------|--|--|
| BC856S_2 | 20090219 | Product data sheet | - | BC856S_1 | | |
| Modifications: | The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. | | | | | |
| | Legal texts have been adapted to the new company name where appropriate. | | | | | |
| | <u>Section 1.2 "Features"</u>: adapted | | | | | |
| | Section 4 "Marking": updated | | | | | |
| | Section 7 "C | haracteristics": enhanced | | | | |
| | Section 9 "Packing information": added | | | | | |
| | Section 10 "Soldering": added | | | | | |
| | Section 12 " | Legal information": updated | | | | |
| BC856S 1 | 19990824 | Product specification | - | - | | |

12. Legal information

12.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Date of release: 19 February 2009 Document identifier: BC856S_2



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